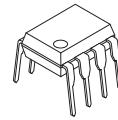


LOW VOLTAGE OPERATION LOW OFFSET VOLTAGE DUAL C-MOS OPERATIONAL AMPLIFIER

■ GENERAL DESCRIPTION

The NJU7094, 95 and 96 are single supply dual C-MOS operational amplifiers featuring a low operating voltage from 1V, low operating current of 15 μ A/circuit (7094 typ.), 80 μ A/circuit (7095 typ.), 200 μ A/circuit (7096 typ.) and low offset voltage 2mV (max.). They also have a low input bias current of 1pA (typ.) and input voltage range from ground, which can provide a ground sensing, and rail-to-rail output swing in both rails. The NJU7094, 7095 and 7096 are available in a wide variety of 8-lead packages, dual-in-line DIP8, surface-mount SOP8 (DMP8), SSOP8, MSOP8 (VSP8), MSOP8 (TVSP8). The combination of these features makes them ideal for a variety of portable devices.

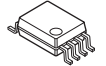
■ PACKAGE OUTLINE



NJU709XD
(DIP8)



NJU709XM
(DMP8)



NJU709XV
(SSOP8)



NJU709XR
(MSOP8 (VSP8))

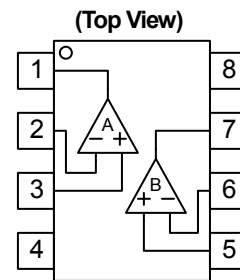


NJU709XRB1
(MSOP8 (TVSP8))

■ FEATURES

- Single-Power-Supply
- Low Offset Voltage ($V_{IO}=4\text{mV max}$)
- Wide Operating Voltage ($V_{DD}=1 \text{ to } 5.5\text{V}$)
- Wide Output Swing Range ($V_{OM}=2.9\text{V min. @ } 3.0\text{V}$)
- Low Operating Current
- Low Bias Current ($I_{IB}=1\text{pA typ.}$)
- Compensation Capacitor Incorporated
- Package Outline
DIP8, DMP8, SSOP8
MSOP8 (VSP8) MEET JEDEC MO-187-DA
MSOP8 (TVSP8) MEET JEDEC MO-187-DA/ THIN TYPE

■ PIN CONFIGURATION



- 1: OUT 1
- 2: IN -1
- 3: IN +1
- 4: VSS
- 5: IN +2
- 6: IN -2
- 7: OUT 2
- 8: VDD

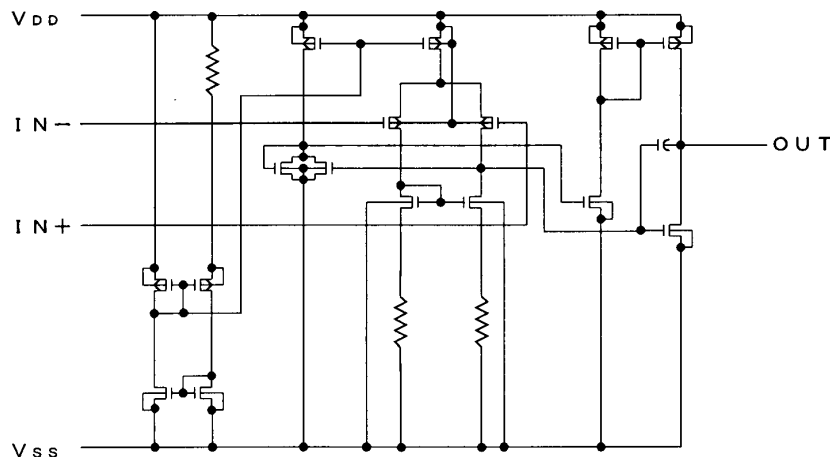
- C-MOS Technology

■ LINE-UP

($T_a=25^\circ\text{C}, V_{DD}=3.0\text{V}, \text{Per Circuit}$)

PARAMETER	NJU7094	NJU7095	NJU7096	UNIT
Operating Current	15	80	200	μA (typ)
Slew Rate	0.1	1.0	2.4	$\text{V}/\mu\text{s}$ (typ)
Unity Gain Bandwidth	0.2	1.0	1.0	MHz (typ)

■ EQUIVALENT CIRCUIT



NJU7094/95/96

■ ABSOLUTE MAXIMUM RATINGS

(Ta=25°C)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V _{DD}	7	V
Differential Input Voltage	V _{ID}	± 7 (note1)	V
Common Mode Input Voltage	V _{IC}	-0.3~7	V
Power Dissipation	P _D	(DIP8) 500 (DMP8) 300 (SSOP8) 250 (MSOP8 (VSP8)) 320 (MSOP8 (TVSP8)) 320	mW
Operating Temperature Range	T _{opr}	-40~+85	°C
Storage Temperature Range	T _{stg}	-55~+125	°C

(note1) If the supply voltage (V_{DD}) is less than 7V, the input voltage must not over the V_{DD} level though 7V is limit specified.

(note2) Decoupling capacitor should be connected between V_{DD} and V_{SS} for the stable operation.

■ ELECTRICAL CHARACTERISTICS

NJU7094

(Ta=25°C, V_{DD}=3.0V, R_L=∞)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Input Offset Voltage	V _{IO}	V _{IN} =1/2V _{DD}	-	-	4	mV
Input Offset Current	I _{IO}		-	1	-	pA
Input Bias Current	I _{IB}		-	1	-	pA
Input Impedance	R _{IN}		-	1	-	TΩ
Large Signal Voltage Gain	A _{VD}		60	70	-	dB
Input Common Mode Voltage Range	V _{ICM}		0~2.5	-	-	V
Maximum Output Swing Voltage	V _{OM1}	R _L =1MΩ	V _{DD} -0.1	-	-	V
	V _{OM2}	R _L =1MΩ	-	-	V _{SS} +0.1	V
Common Mode Rejection Ratio	CMR	V _{IN} =1/2V _{DD}	55	65	-	dB
Supply Voltage Rejection Ratio	SVR	V _{DD} =1.5~5.5V	60	70	-	dB
Operating Current	I _{DD}	Per Circuit	-	15	25	μA
Slew Rate	SR		-	0.1	-	V/μs
Unity Gain Bandwidth	F _t	A _v =40dB, C _L =10pF	-	0.2	-	MHz

(note3) The source current is less than 2.9μA (at V_{OM}/R_L=2.9V/1MΩ).

NJU7095

(Ta=25°C, V_{DD}=3.0V, R_L=∞)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Input Offset Voltage	V _{IO}	V _{IN} =1/2V _{DD}	-	-	4	mV
Input Offset Current	I _{IO}		-	1	-	pA
Input Bias Current	I _{IB}		-	1	-	pA
Input Impedance	R _{IN}		-	1	-	TΩ
Large Signal Voltage Gain	A _{VD}		60	70	-	dB
Input Common Mode Voltage Range	V _{ICM}		0~2.5	-	-	V
Maximum Output Swing Voltage	V _{OM1}	R _L =100kΩ	V _{DD} -0.1	-	-	V
	V _{OM2}	R _L =100kΩ	-	-	V _{SS} +0.1	V
Common Mode Rejection Ratio	CMR	V _{IN} =1/2V _{DD}	55	65	-	dB
Supply Voltage Rejection Ratio	SVR	V _{DD} =1.5~5.5V	60	70	-	dB
Operating Current	I _{DD}	Per Circuit	-	80	160	μA
Slew Rate	SR		-	1.0	-	V/μs
Unity Gain Bandwidth	F _t	A _V =40dB, C _L =10pF	-	1.0	-	MHz

(note4) The source current is less than 29μA (at V_{OM}/R_L=2.9V/100kΩ).

NJU7096

(Ta=25°C, V_{DD}=3.0V, R_L=∞)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Input Offset Voltage	V _{IO}	V _{IN} =1/2V _{DD}	-	-	4	mV
Input Offset Current	I _{IO}		-	1	-	pA
Input Bias Current	I _{IB}		-	1	-	pA
Input Impedance	R _{IN}		-	1	-	TΩ
Large Signal Voltage Gain	A _{VD}		60	70	-	dB
Input Common Mode Voltage Range	V _{ICM}		0~2.5	-	-	V
Maximum Output Swing Voltage	V _{OM1}	R _L =50kΩ	V _{DD} -0.1	-	-	V
	V _{OM2}	R _L =50kΩ	-	-	V _{SS} +0.1	V
Common Mode Rejection Ratio	CMR	V _{IN} =1/2V _{DD}	55	65	-	dB
Supply Voltage Rejection Ratio	SVR	V _{DD} =1.5~5.5V	60	70	-	dB
Operating Current	I _{DD}	Per Circuit	-	200	400	μA
Slew Rate	SR		-	2.4	-	V/μs
Unity Gain Bandwidth	F _t	A _V =40dB, C _L =10pF	-	1.0	-	MHz

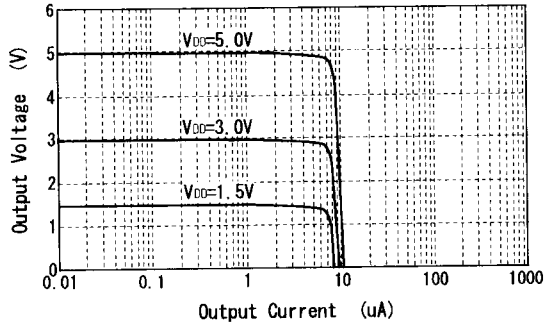
(note5) The source current is less than 58μA (at V_{OM}/R_L=2.9V/50kΩ).

NJU7094/95/96

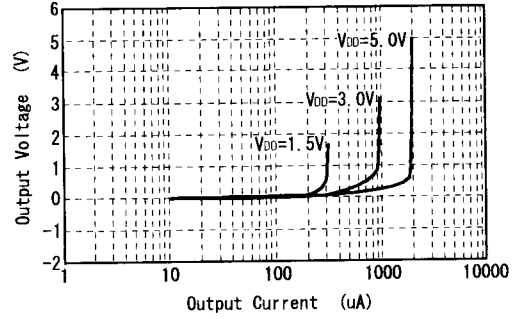
■ TYPICAL CHARACTERISTICS

(1) NJU7094

Output Voltage vs. Output Current (SOURCE)

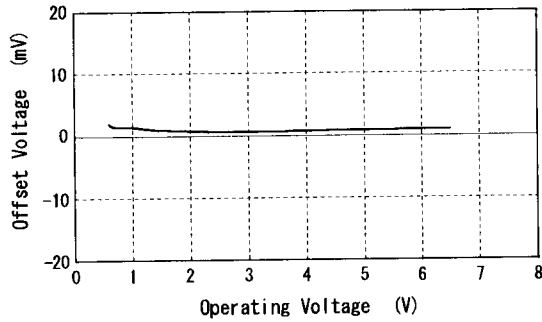


Output Voltage vs. Output Current (SINK)



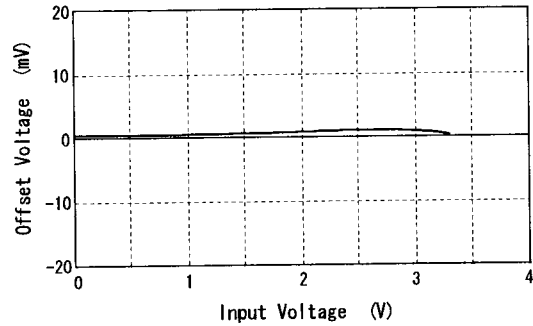
Offset Voltage vs. Operating Voltage

V_{IN}=0.1V



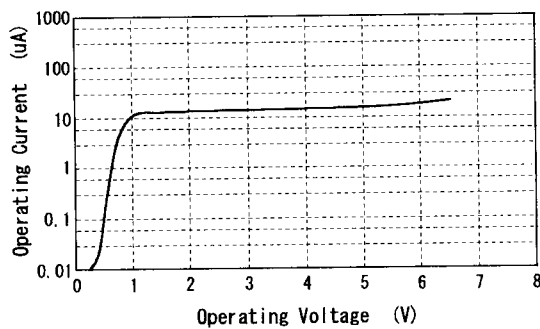
Offset Voltage vs. Input Voltage

V_{DD}=3.0V



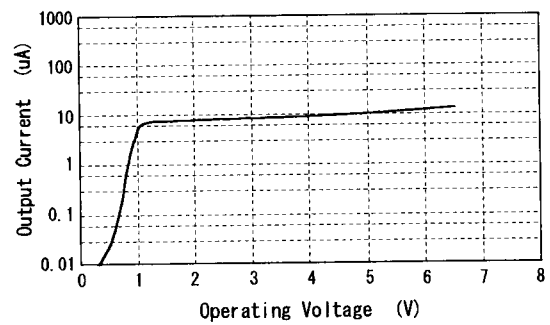
Operating Current vs. Operating Voltage

V_{IN}=0.1V

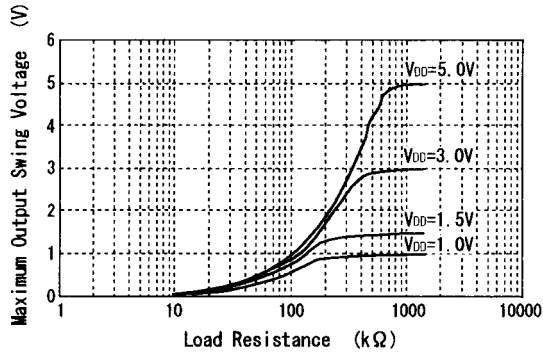


Output Current vs. Operating Voltage

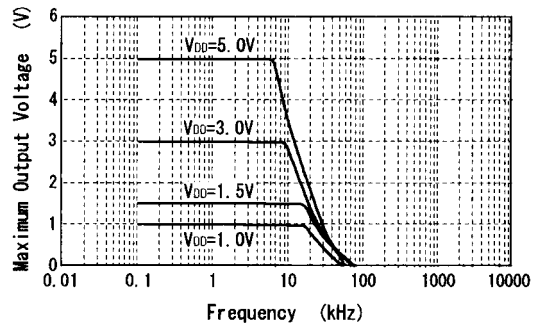
V_{IN}=0.1V



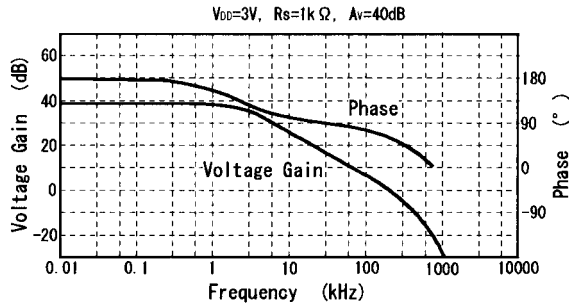
Maximum Output Swing Voltage vs. Load Resistance



Maximum Output Swing Voltage vs. Frequency

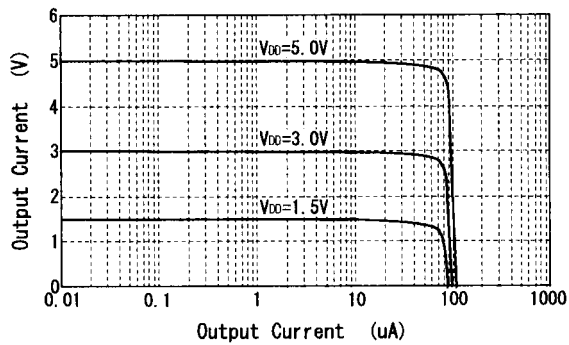


Voltage Gain-Phase vs. Frequency

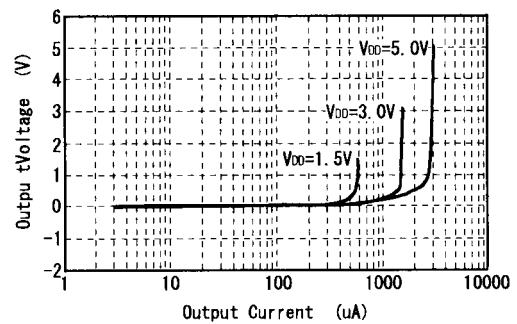


(2) NJU7095

Output Voltage vs. Output Current (SOURCE)

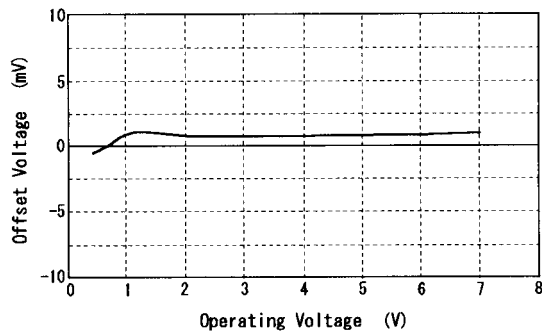


Output Voltage vs. Output Current (SINK)



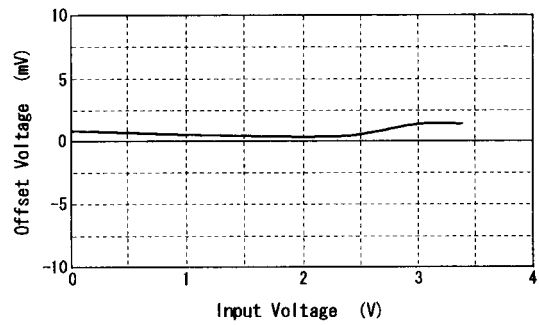
Offset Voltage vs. Operating Voltage

$V_{IN}=0.1V$



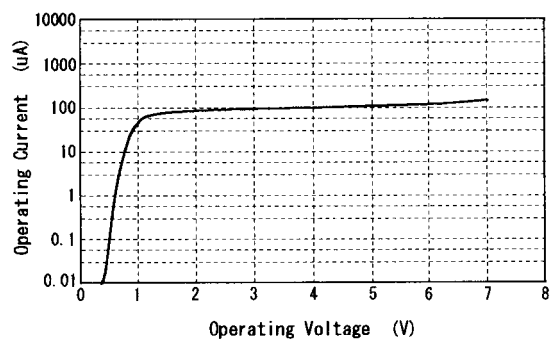
Offset Voltage vs. Input Voltage

$V_{DD}=3.0V$



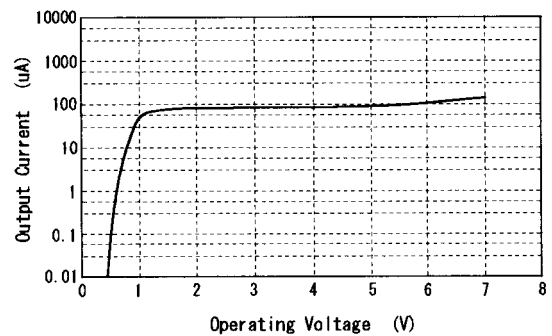
Operating Current vs. Operating Voltage

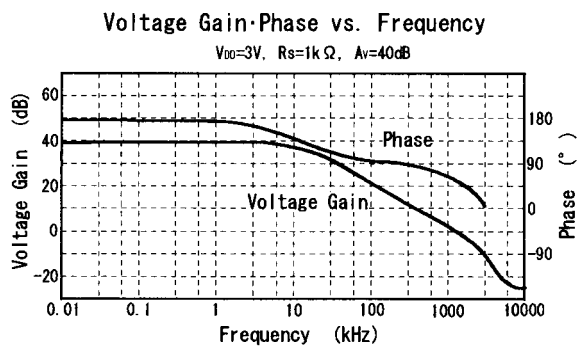
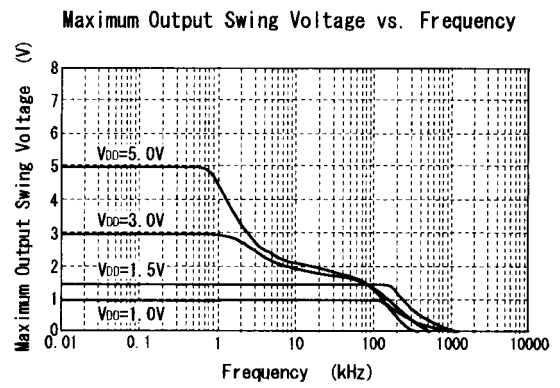
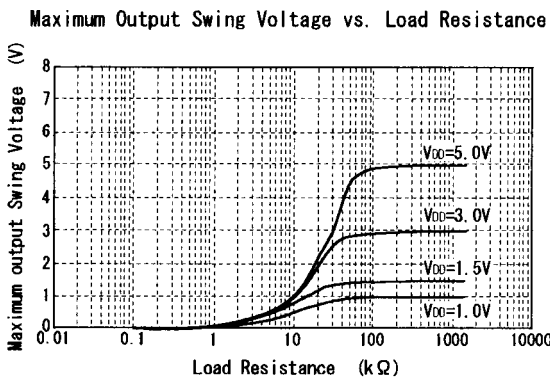
$V_{IN}=0.1V$



Output Current vs. Operating Voltage

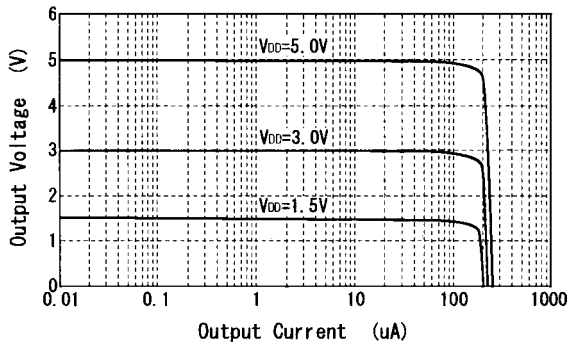
$V_{IN}=0.1V$



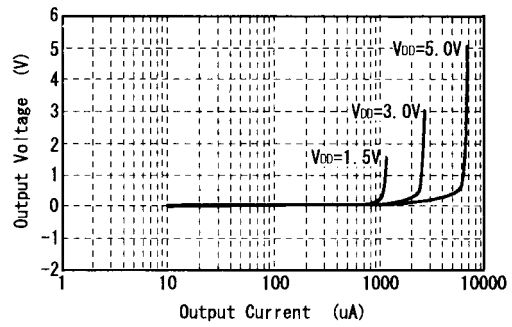


(3) NJU7096

Output Voltage vs. Output Current (SOURCE)

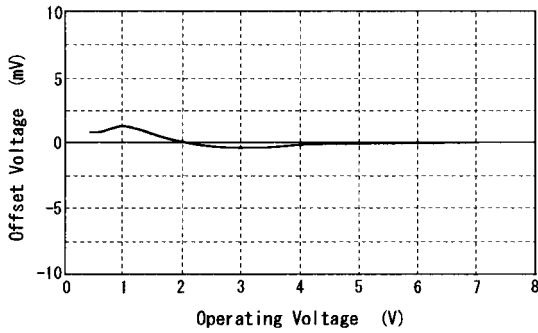


Output Voltage vs. Output Current (SINK)



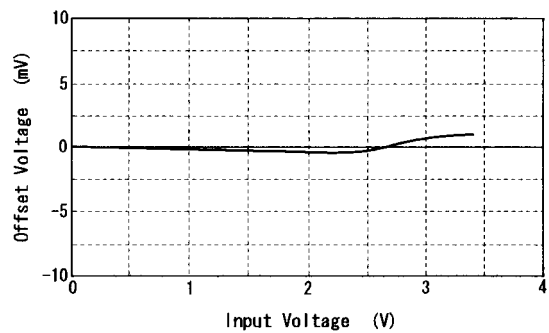
Offset Voltage vs. Operating Voltage

V_{IN}=0.1V



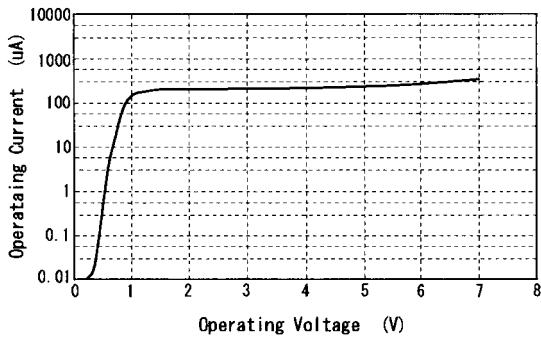
Offset Voltage vs. Input Voltage

V_{DD}=3.0V



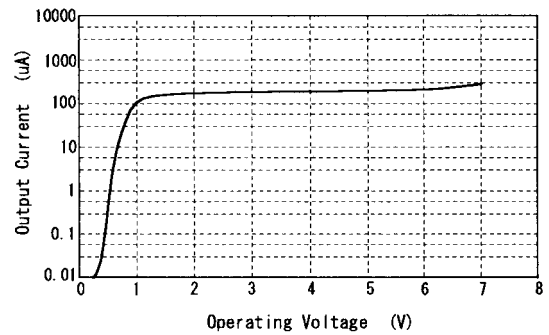
Operating Current vs. Operating Voltage

V_{IN}=0.1V

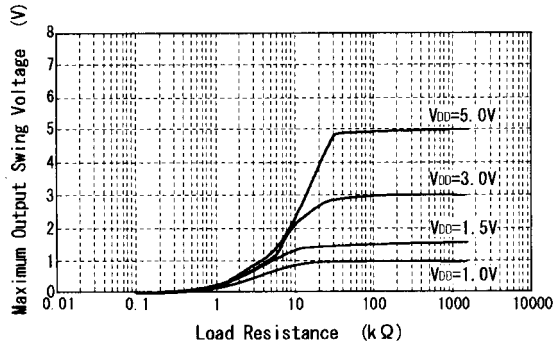


Output Current vs. Operating Voltage

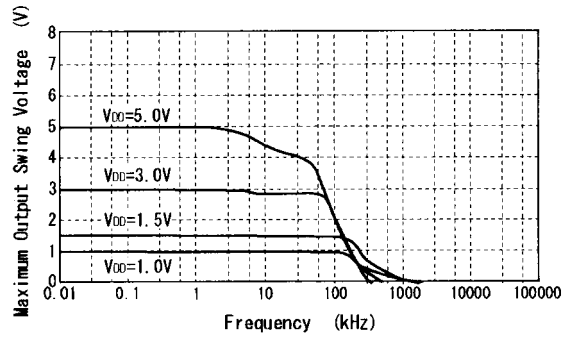
V_{IN}=0.1V



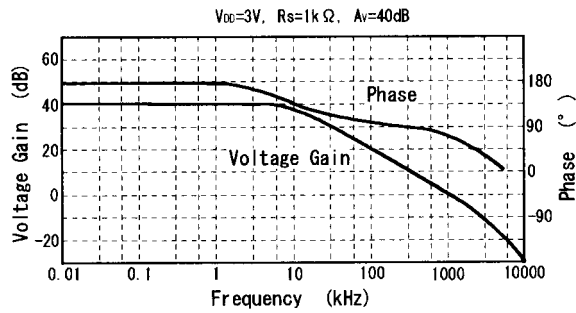
Maximum Output Swing Voltage vs. Load Resistance



Maximum Output Swing Voltage vs. Frequency



Voltage Gain-Phase vs. Frequency



[CAUTION]

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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.